

S2386 series

For visible to near IR, general-purpose photometry

Features

- High sensitivity in visible to near infrared range
- Low dark current
- High reliability
- Superior linearity

Applications

- Analytical instruments
- Optical measurement equipment

Structure / Absolute maximum ratings

Type no.	Dimensional outline/ Window material*	Package	Photosensitive area size (mm)	Absolute maximum ratings		
				Reverse voltage V _R max (V)	Operating temperature T _{opr} (°C)	Storage temperature T _{stg} (°C)
S2386-18K	(1)/K	TO-18	1.1 × 1.1	30	-40 to +100	-55 to +125
S2386-18L	(2)/L					
S2386-5K	(3)/K	TO-5	2.4 × 2.4			
S2386-44K	(4)/K		3.6 × 3.6			
S2386-45K	(5)/K		3.9 × 4.6			
S2386-8K	(6)/K	TO-8	5.8 × 5.8			

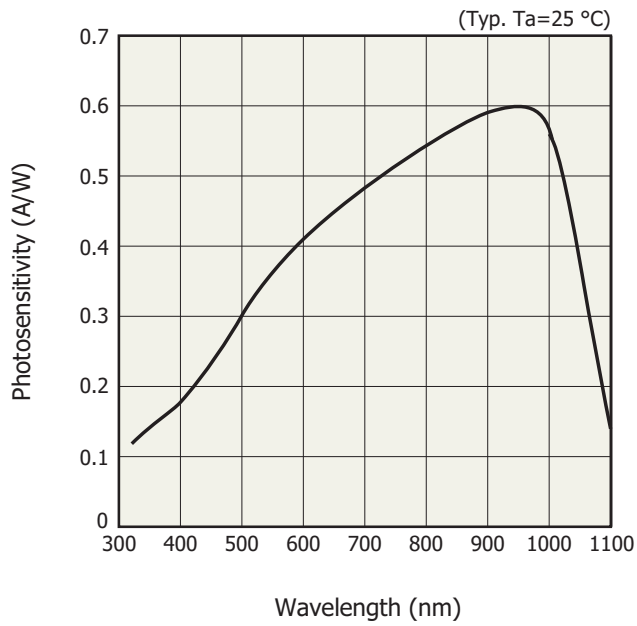
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

* Window material K=borosilicate glass, L=lens type borosilicate glass

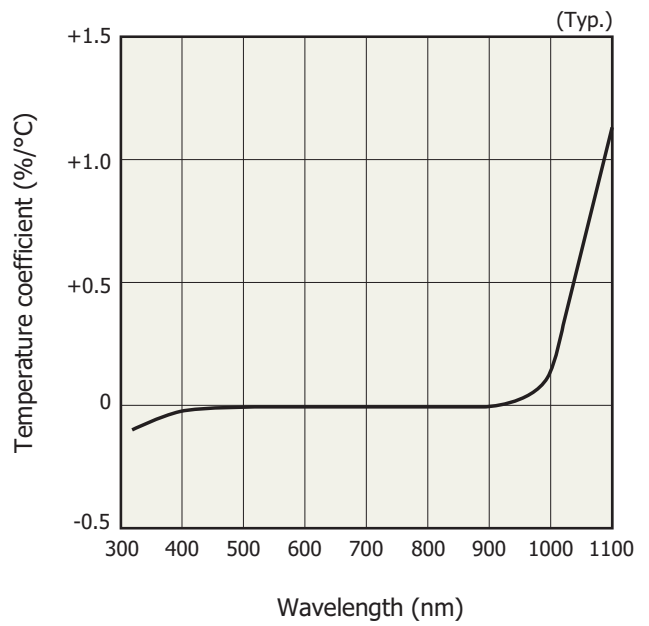
Electrical and optical characteristics (Typ. T_a=25 °C, unless otherwise noted)

Type no.	Spectral response range λ (nm)	Peak sensitivity wavelength λ _p (nm)	Photosensitivity S (A/W)				Short circuit current I _{sc} 100 lx		Dark current I _D V _R =10 mV max. (pA)	Temp. coefficient of I _D T _{CID} (times/°C)	Rise time t _r V _R =0 V R _L =1 kΩ (μs)	Terminal capacitance C _t V _R =0 V f=10 kHz (pF)	Shunt resistance R _{sh} V _R =10 mV		Noise equivalent power NEP V _R =0 V λ=λ _p (W/Hz ^{1/2})			
			λ _p	GaP LED 560 nm	He-Ne laser 633 nm	GaAs LED 930 nm	Min. (μA)	Typ. (μA)					Min. (GΩ)	Typ. (GΩ)				
S2386-18K	320 to 1100	960	0.6	0.38	0.43	0.59	1	1.3	2	1.12	0.4	140	5	100	6.8 × 10 ⁻¹⁶			
S2386-18L							4	5.7										
S2386-5K							4.4	6.0	5				1.8	730		2	50	9.6 × 10 ⁻¹⁶
S2386-44K							9.6	12	20									
S2386-45K							12	17	30				3.6	1600		0.5	25	1.4 × 10 ⁻¹⁵
S2386-8K							26	33	50									
										10	4300	0.2	10	2.1 × 10 ⁻¹⁵				

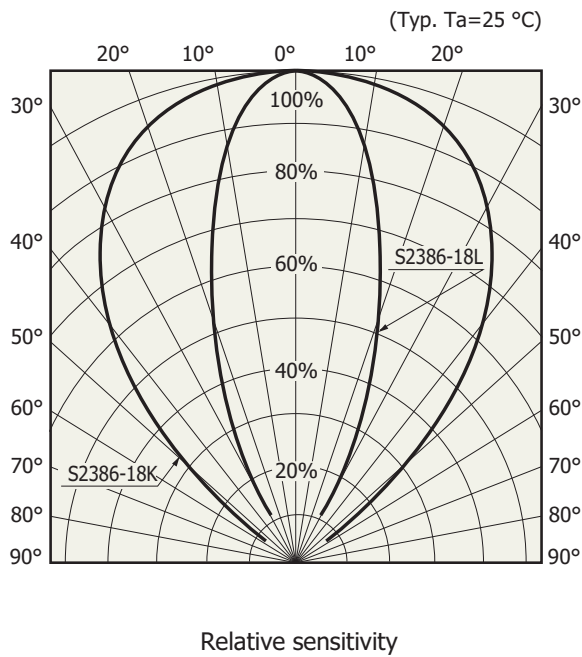
Spectral response



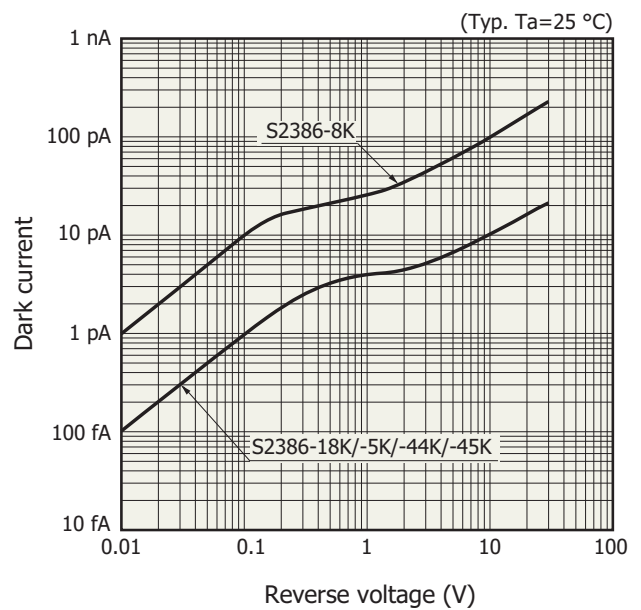
Photosensitivity temperature characteristic



Directivity

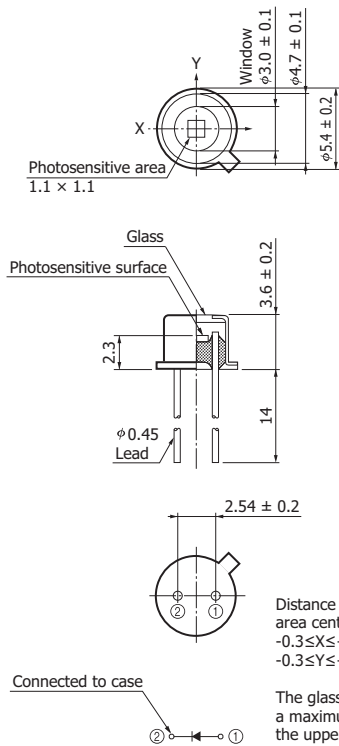


Dark current vs. reverse voltage



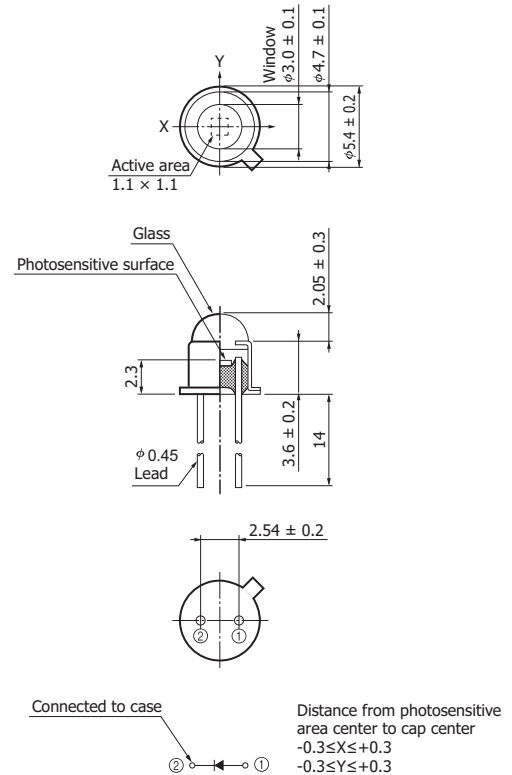
Dimensional outlines (unit: mm)

(1) S2386-18K



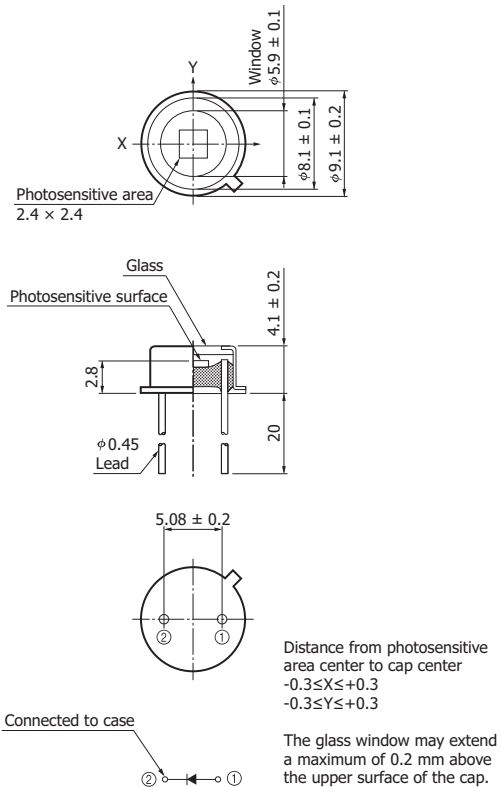
KSPDA0191EC

(2) S2386-18L



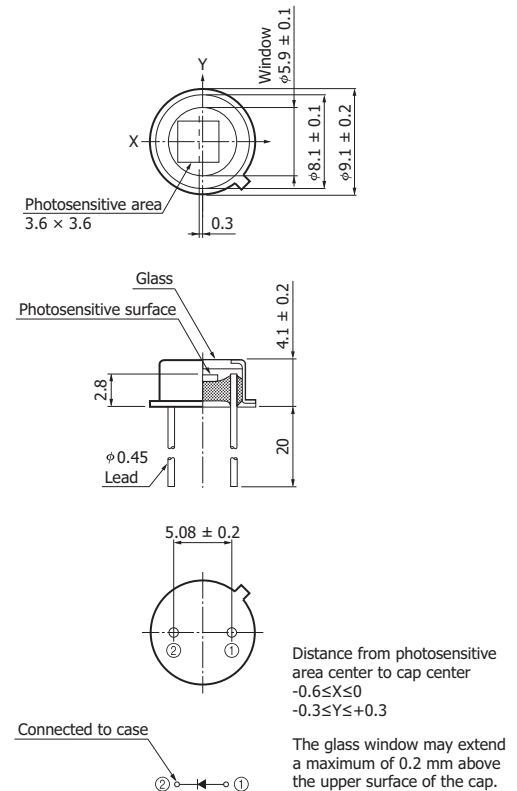
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(3) S2386-5K



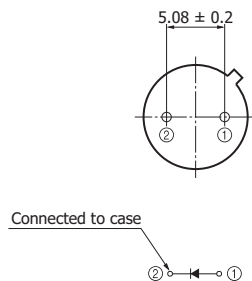
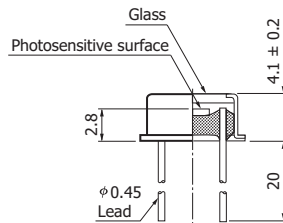
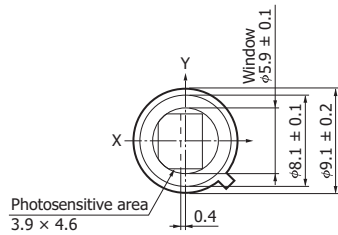
KSPDA0192EC

(4) S2386-44K



KSPDA0193EC

(5) S2386-45K

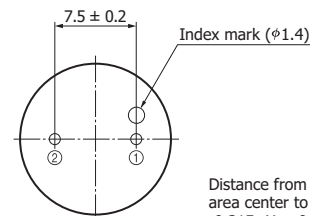
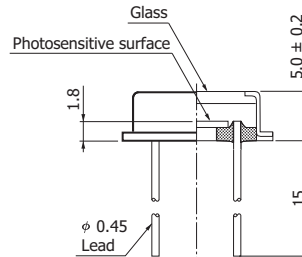
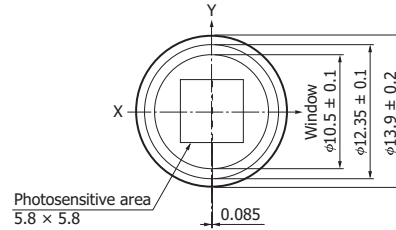


Distance from photosensitive area center to cap center
 $-0.7 \leq X \leq -0.1$
 $-0.3 \leq Y \leq +0.3$

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0178EE

(6) S2386-8K



Distance from photosensitive area center to cap center
 $-0.315 \leq X \leq +0.485$
 $-0.4 \leq Y \leq +0.4$

The glass window may extend a maximum of 0.2 mm above the upper surface of the cap.

KSPDA0194EC

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

Precautions

- Disclaimer
- Metal, ceramic, plastic package products

Technical information

- Si photodiode/Application circuit examples

Information described in this material is current as of August 2017.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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